



**TET ESTEL AS**  
ESTONIA

**February**  
**2016**

**Series**  
**D153-2000**

**Rectifier Press-Pack**  
**Diode**  
**Type D153-2000**

Designed for rectifiers and industrial applications

Maximum mean forward current							$I_{FAV}$	<b>2000 A</b>			
Maximum repetitive peak reverse voltage							$U_{RRM}$	<b>800 ÷ 1800 V</b>			
Reverse recovery time							$t_{rr}$ (typ)	<b>40 <math>\mu</math>s</b>			
$U_{RRM}$ , V	800	900	1000	1100	1200	1300	1400	1500	1600	1800	
Voltage code	8	9	10	11	12	13	14	15	16	18	
$T_{vj}$ , °C	- 60 ÷ 175										

**MAXIMUM ALLOWABLE RATINGS**

Symbols and parameters		Units	D153-2000	Conditions
$I_{FAV}$	Mean forward current	A	2000 3290	$T_c=117\text{ }^\circ\text{C}$ , $T_c=55\text{ }^\circ\text{C}$ , 180° half-sine wave, 50 Hz
$I_{FRMS}$	RMS forward current	A	3140	$T_c=117\text{ }^\circ\text{C}$
$I_{FSM}$	Surge forward current	kA	36 40	$T_{vj}=175\text{ }^\circ\text{C}$ $T_{vj}=25\text{ }^\circ\text{C}$
$I^2t$	Limiting load integral	$\text{kA}^2\text{s}$	6480 8000	$T_{vj}=175\text{ }^\circ\text{C}$ $T_{vj}=25\text{ }^\circ\text{C}$
$U_{RRM}$	Repetitive peak reverse voltage	V	800÷1800	$T_j \min \leq T_{vj} \leq T_{jM}$ 180° half-sine wave, 50 Hz
$U_{RSM}$	Non-repetitive peak reverse voltage	V	900÷1900	$T_j \min \leq T_{vj} \leq T_{jM}$ 180° half-sine wave $t_p=10\text{ ms}$ , Single pulse
$T_{stg}$	Storage temperature	°C	-60÷80	
$T_{vj}$	Junction temperature	°C	-60÷175	

**CHARACTERISTICS**

$U_{FM}$	Peak forward voltage	V	1,7	$T_{vj}=25\text{ }^\circ\text{C}$ , $I_{TM}=3,14 I_{TAV}$
$U_{F(TO)}$	Threshold voltage	V	0,83	$T_{vj}=175\text{ }^\circ\text{C}$ $1,57 I_{TAV} < I_T < 4,71 I_{TAV}$
$R_T$	Forward slope resistance	$\text{m}\Omega$	0,12	
$I_{RRM}$	Repetitive peak reverse current	mA	90	$T_{vj}=175\text{ }^\circ\text{C}$ , $U_R = U_{RRM}$

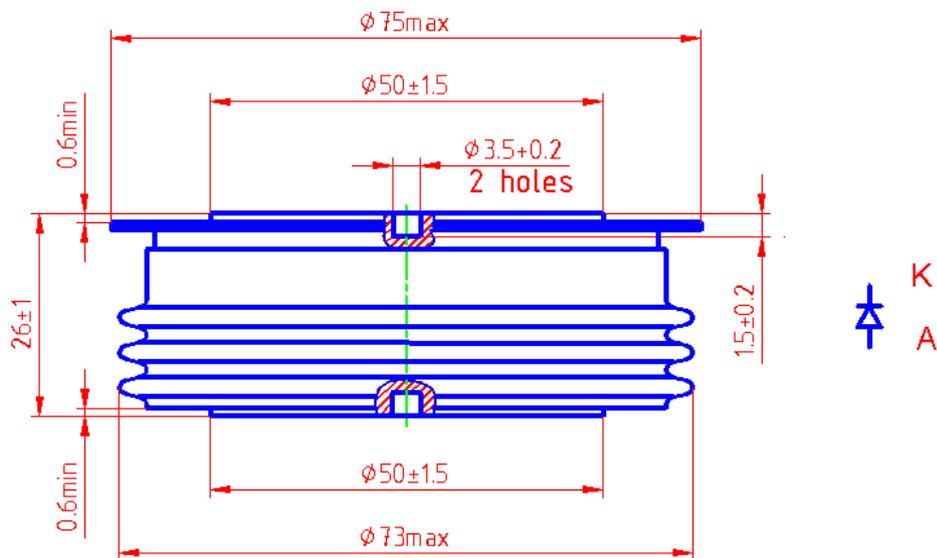
## CHARACTERISTICS

Symbols and parameters		Units	D153-2000	Conditions
Q <sub>rr</sub>	Recovered charge (typ)	μC	3500	T <sub>vj</sub> =175°C I <sub>F</sub> =2000 A di <sub>R</sub> /dt =10 A/μs U <sub>R</sub> =100V
t <sub>rr</sub>	Reverse recovery time (typ)	μs	40	
I <sub>rrm</sub>	Peak reverse recovery current (typ)	A	175	
R <sub>thjc</sub>	Thermal resistance junction to case	°C/W	0,02	Direct current, double side cooled

## ORDERING

	<b>D</b>	<b>153</b>	<b>2000</b>	<b>18</b>	
	<b>1</b>	<b>2</b>	<b>3</b>	<b>4</b>	

1. Diode
2. Design version
3. Mean forward current, A
4. Voltage code (18=1800 V)



Mounting force : 19 ÷ 28 kN  
Weight : 580 grams